

TPDxE05U06 超高速 (最大 6Gbps) インターフェイス用 1/4/6 チャンネル ESD 保護デバイス

1 特長

- IEC 61000-4-2 レベル 4 ESD 保護
 - ±12kV 接触放電
 - ±15kV エアギャップ放電
- IEC 61000-4-4 EFT 保護
 - 80A (5/50ns)
- IEC 61000-4-5 サージ保護
 - 2.5A (8/20μs)
- IO 容量: 0.42pF ~ 0.5pF (標準値)
- DC ブレークダウン電圧: 6.5V (最小値)
- 超低リーク電流: 10nA (最大値)
- 低 ESD クランプ電圧
- 産業用温度範囲: -40°C ~ +125°C
- 使いやすいストレートルーティングパッケージ
- 業界標準の SOD-523 パッケージ (1.60mm × 0.80mm × 0.65mm)

2 アプリケーション

- [HDMI 1.4b](#)
- HDMI 2.0
- [USB 3.0](#)
- MHL
- [LVDS インターフェイス](#)
- [DisplayPort](#)
- [PCI-express®](#)
- [eSata インターフェイス](#)
- [V-by-One® HS](#)

3 概要

TPDxE05U06 は、超低容量の単方向過渡電圧サプレッサ (TVS) ベース静電気放電 (ESD) 保護ダイオードファミリです。各デバイスは、IEC 61000-4-2 国際規格で規定されている最大レベルを上回る ESD のエネルギーを消費できます。TPDxE05U06 は負荷容量が非常に小さいため、あらゆる高速信号ピンを保護するのに理想的なデバイスです。

TPDxE05U06 の代表的なアプリケーションには、HDMI 1.4b、HDMI 2.0、USB 3.0、MHL、LVDS、DisplayPort、PCI-Express®, eSata および V-by-One® HS の高速信号ラインが含まれます。

製品情報

部品番号	チャンネル数	パッケージ (1)
TPD1E05U06	1 チャンネル	DPY (X1SON, 2)
		DYA (SOD-523, 2)
TPD4E05U06	4 チャンネル	DQA (USON, 10)
TPD6E05U06	6 チャンネル	RVZ (USON, 14)

(1) 詳細については、[セクション 10](#) を参照してください。

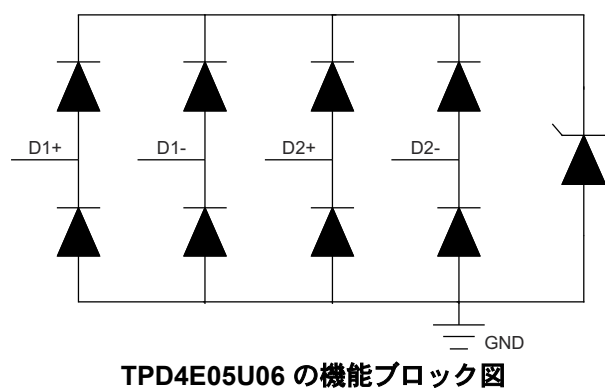
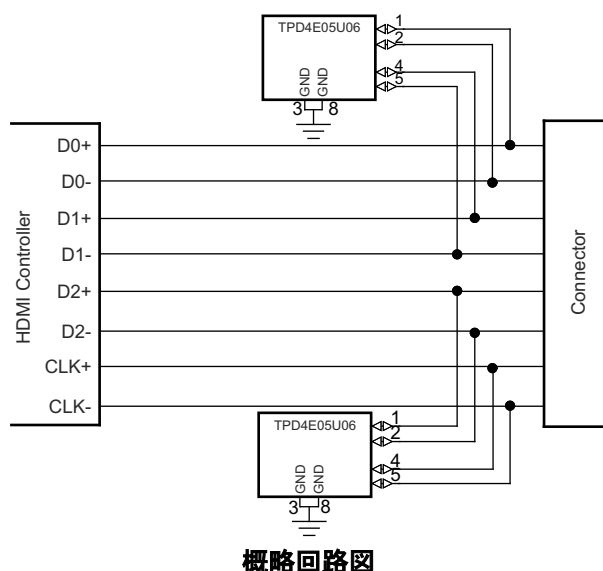


Table of Contents

1 特長	1	7 Application and Implementation	12
2 アプリケーション	1	7.1 Application Information.....	12
3 概要	1	7.2 Typical Applications.....	12
4 Pin Configuration and Functions	3	7.3 Power Supply Recommendations.....	15
5 Specifications	6	7.4 Layout.....	15
Absolute Maximum Ratings.....	6	8 Device and Documentation Support	18
5.1 ESD Ratings—JEDEC Specification.....	6	8.1 Documentation Support.....	18
5.2 ESD Ratings—IEC Specification.....	6	8.2 ドキュメントの更新通知を受け取る方法.....	18
Recommended Operating Conditions.....	6	8.3 サポート・リソース.....	18
5.3 Thermal Information.....	7	8.4 Trademarks.....	18
5.4 Electrical Characteristics.....	7	8.5 静電気放電に関する注意事項.....	18
5.5 Typical Characteristics.....	8	8.6 用語集.....	18
6 Detailed Description	10	9 Revision History	18
6.1 Overview.....	10	10 Mechanical, Packaging, and Orderable Information	19
6.2 Functional Block Diagram.....	10	10.1 Tape and Reel Information.....	19
6.3 Feature Description.....	11	10.2 Mechanical Data.....	21
6.4 Device Functional Modes.....	11		

4 Pin Configuration and Functions

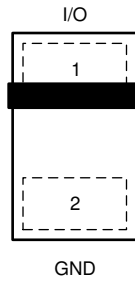


図 4-1. DPY Package 2-Pin X1SON (Top View)

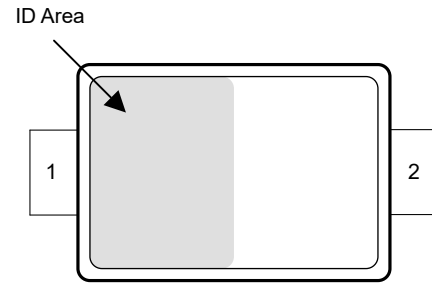


図 4-2. DYA Package 2-Pin SOD-523 (Top View)

表 4-1. Pin Functions TPD1E05U06 DPY and DYA

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
GND	2	Ground	Ground; Connect to ground
I/O	1	I/O	ESD protected channel ⁽²⁾

(1) I = input, O = output

(2) Place as close to the connector as possible.

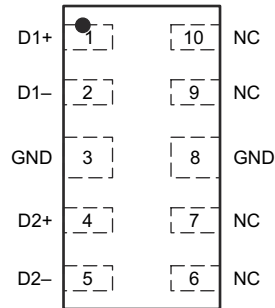


図 4-3. DQA Package 10-Pin USON (Top View)

表 4-2. Pin Functions TPD4E05U06 DQA

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
D1+	1	I/O	ESD protected channel ⁽²⁾
D1–	2	I/O	ESD protected channel ⁽²⁾
D2+	4	I/O	ESD protected channel ⁽²⁾
D2–	5	I/O	ESD protected channel ⁽²⁾
GND	3	Ground	Ground; Connect to ground
GND	8		
NC	6	—	Not connected; Used for optional straight-through routing. Can be left floating or grounded
NC	7		
NC	9		
NC	10		

(1) I = input, O = output

(2) Place as close to the connector as possible.

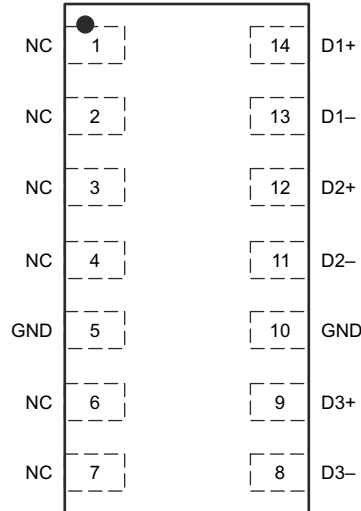


図 4-4. RVZ Package 14-Pin USON (Top View)

表 4-3. Pin Functions TPD6E05U06 RVZ

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
D1+	14	I/O	ESD protected channel ⁽²⁾
D1-	13	I/O	ESD protected channel ⁽²⁾
D2+	12	I/O	ESD protected channel ⁽²⁾
D2-	11	I/O	ESD protected channel ⁽²⁾
D3+	9	I/O	ESD protected channel ⁽²⁾
D3-	8	I/O	ESD protected channel ⁽²⁾
GND	5	Ground	Ground; Connect to ground
GND	10		
NC	1	—	Not connected; Used for optional straight-through routing. Can be left floating or grounded
NC	2		
NC	3		
NC	4		
NC	6		
NC	7		

- (1) I = input, O = output
 (2) Place as close to the connector as possible.

5 Specifications

Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Electrical Fast Transient ⁽²⁾ ⁽³⁾	IEC 61000-4-4 (5/50ns)		80	A
Peak Pulse ⁽²⁾ ⁽³⁾	IEC 61000-4-5 Current (8/20us)		2.5	A
	IEC 61000-4-5 Power (8/20us)		40	W
T _A	Ambient Operating Temperature	-40	125	°C
T _{stg}	Storage Temperature	-65	155	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Voltages are with respect to GND unless otherwise noted.
- (3) Measured at 25°C

5.1 ESD Ratings—JEDEC Specification

			VALUE	UNIT
V _(ESD)	Electrostatic discharge – DPY, DQA, and RVZ	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001 ⁽¹⁾	±4000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1500	V
V _(ESD)	Electrostatic discharge – DYA	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001	±2500	V
		Charged device model (CDM), per JEDEC specification JS-002	±1000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions. Pins listed as ±4000 V may actually have higher performance.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions. Pins listed as ±1500 V may actually have higher performance.

5.2 ESD Ratings—IEC Specification

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	IEC 61000-4-2 contact discharge	±12000	V
		IEC 61000-4-2 air-gap discharge	±15000	

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{IO}	Input pin voltage	0		5.5	V
T _A	Operating free-air temperature	-40		125	°C

5.3 Thermal Information

THERMAL METRIC ⁽¹⁾		TPD1E05U06		TPD4E05U06	TPD6E05U06	UNIT
		DPY (X1SON)	DYA (SOD523)	DQA (USON)	RVZ (USON)	
		2 PINS	2 PINS	10 PINS	14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	697.3	772.1	327	197.9	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	471	444.6	189.5	119.1	°C/W
R _{θJB}	Junction-to-board thermal resistance	575.9	540.4	257.7	92.6	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	175.7	159.9	60.9	22	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	575.1	533.9	257	91.6	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

5.4 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITION		MIN	TYP	MAX	UNIT
INPUT - OUTPUT RESISTANCE							
V _{RWM}	Reverse stand-off voltage	I _{IO} < 10 μA				5.5	V
V _{BR}	Break-down voltage	I _{IO} = 1 mA		6.5		8.5	V
V _{Clamp}	Clamp voltage	I _{PP} = 1 A, TLP, from I/O to GND ⁽¹⁾			10		V
		I _{PP} = 5 A, TLP, from I/O to GND ⁽¹⁾			14		
		I _{PP} = 1 A, TLP, from GND to I/O ⁽¹⁾			3		
		I _{PP} = 5 A, TLP, from GND to I/O ⁽¹⁾			7		
I _{LEAK}	Leakage current	V _{IO} = 2.5 V			0.01	10	nA
R _{DYN}	Dynamic resistance	DPY package	I/O to GND ⁽²⁾		0.8		Ω
			GND to I/O ⁽²⁾		0.8		
		DYA package	I/O to GND ⁽²⁾		0.8		
			GND to I/O ⁽²⁾		0.7		
		DQA package	I/O to GND ⁽²⁾		0.8		
			GND to I/O ⁽²⁾		0.8		
		RVZ package	I/O to GND ⁽²⁾		0.8		
			GND to I/O ⁽²⁾		0.8		
CAPACITANCE							
C _L	Line capacitance ⁽³⁾	V _{IO} = 2.5 V; f = 1 MHz, I/O to GND	TPD1E05U06 DPY package		0.42		pF
			TPD1E05U06 DYA package		0.42		
			TPD4E05U06 DQA package		0.5		
			TPD6E05U06 RVZ package		0.47		
Δ C _{IO-TO-GND}	Variation of input capacitance	GND Pin = 0 V, f = 1 MHz, VBIAS = 2.5 V, Channel x pin to GND – channel y pin to GND			0.05	0.07	pF
C _{CROSS}	Channel to channel input capacitance	GND Pin = 0 V, f = 1 MHz, VBIAS = 2.5 V, between channel pins			0.01	0.06	pF

- (1) Transition line pulse with 100 ns width, 200 ps rise time.
(2) Extraction of R_{DYN} using least squares fit of TLP characteristics between I = 10 A and I = 20 A.
(3) Capacitance data is taken at 25°C.

5.5 Typical Characteristics

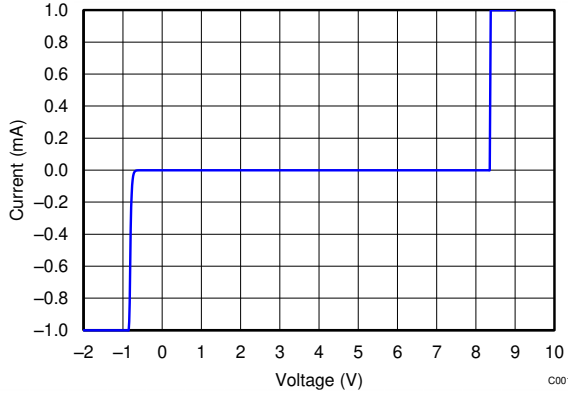


图 5-1. DC Voltage Sweep I-V Curve

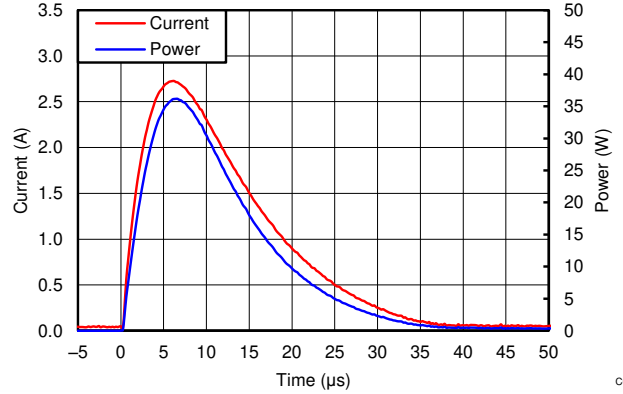


图 5-2. Surge Curve ($t_p = 8/20 \mu s$), Pin IO to GND

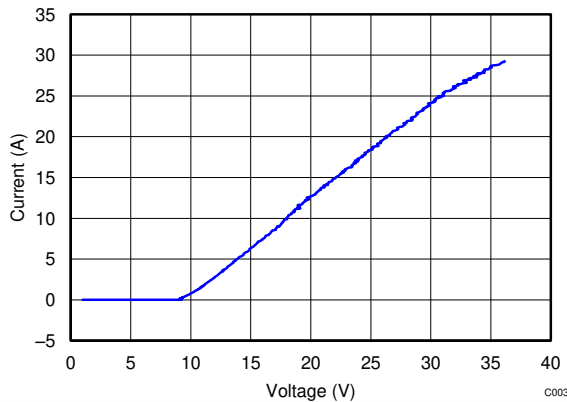


图 5-3. Positive TLP Plot IO to GND

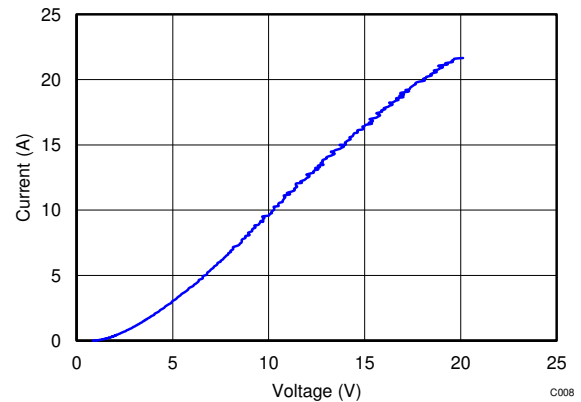


图 5-4. Negative TLP Plot IO to GND

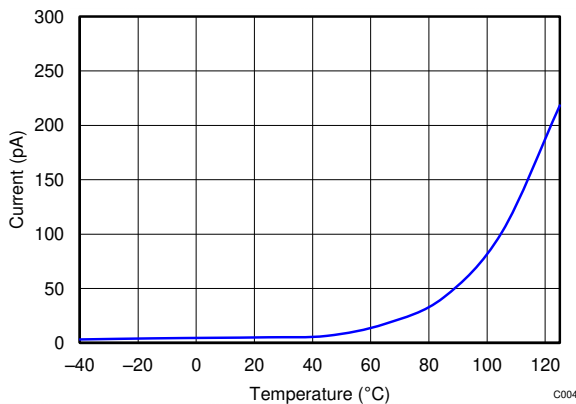


图 5-5. Leakage vs Temperature

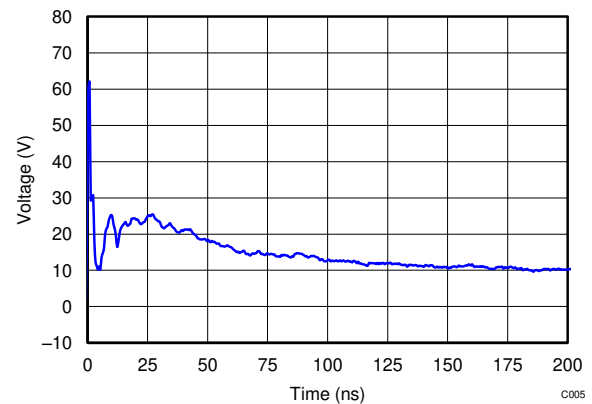


图 5-6. 8-kV IEC Waveform

5.5 Typical Characteristics (continued)

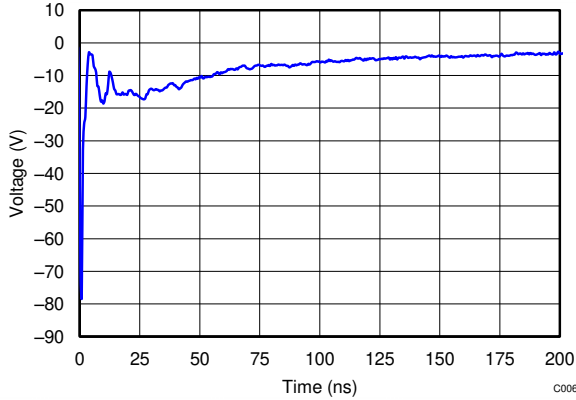


図 5-7. -8-kV IEC Waveform

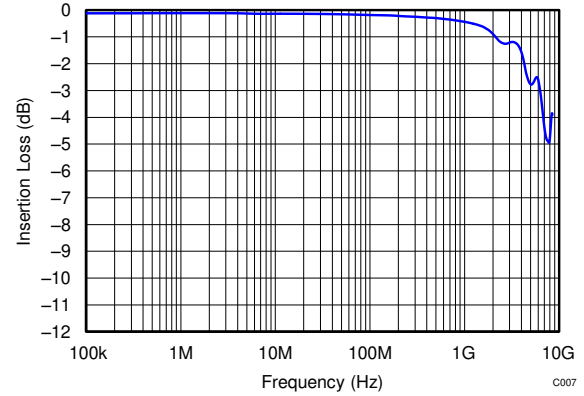


図 5-8. TPD1E05U06 Insertion Loss

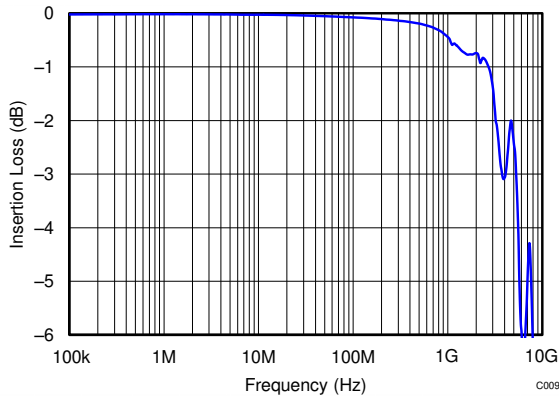


図 5-9. TPD4E05U06 Insertion Loss

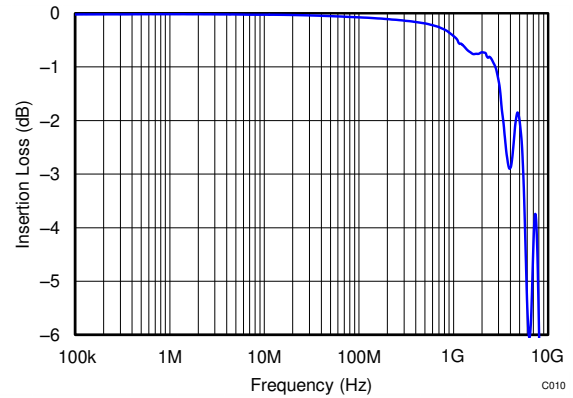


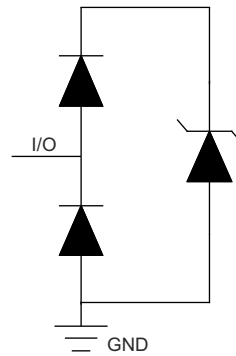
図 5-10. TPD6E05U06 Insertion Loss

6 Detailed Description

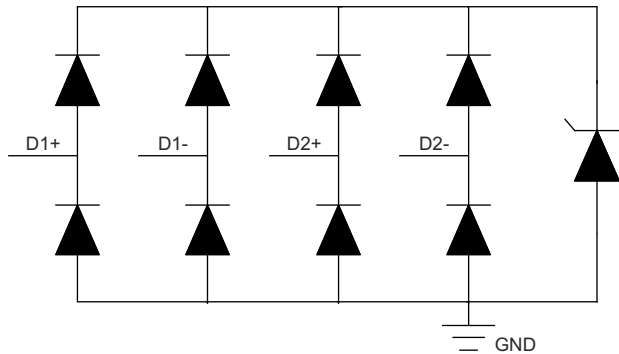
6.1 Overview

The TPDxE05U06 is a family of unidirectional Transient Voltage Suppressor (TVS) based Electrostatic Discharge (ESD) protection diodes with ultra-low capacitance. Each device can dissipate ESD strikes above the maximum level specified by the IEC 61000-4-2 international standard. The TPDxE05U06 ultra-low loading capacitance makes the device an excellent choice for protecting any high-speed signal pins.

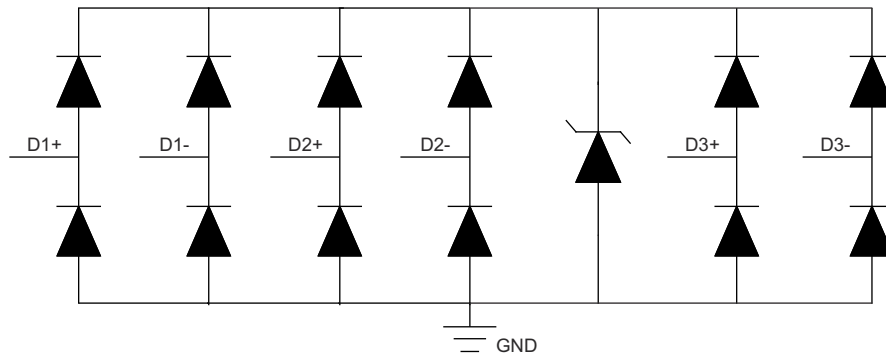
6.2 Functional Block Diagram



6-1. TPD1E05U06 Block Diagram



6-2. TPD4E05U06 Block Diagram



6-3. TPD6E05U06 Block Diagram

6.3 Feature Description

The TPDxE05U06 is a family of unidirectional Transient Voltage Suppressor (TVS) Electrostatic Discharge (ESD) protection diodes with ultra-low capacitance. Each device can dissipate ESD strikes above the maximum level specified by the IEC 61000-4-2 international standard. The TPDxE05U06s ultra-low loading capacitance makes it an excellent choice for protecting any high-speed signal pins.

6.3.1 ± 15 -kV IEC61000-4-2 Level 4 ESD Protection

The I/O pins can withstand ESD events up to ± 12 -kV contact and ± 15 -kV air. An ESD-surge clamp diverts the current to ground.

6.3.2 IEC61000-4-4 EFT Protection

The I/O pins can withstand an electrical fast transient burst of up to 80 A (5/50 ns waveform, 4 kV with 50- Ω impedance). An ESD-surge clamp diverts the current to ground. This has been validated on the TPD4E05U06 only.

6.3.3 IEC61000-4-5 Surge Protection

The I/O pins can withstand surge events up to 2.5 A and 40 W (8/20 μ s waveform). An ESD-surge clamp diverts this current to ground.

6.3.4 I/O Capacitance

The capacitance between each I/O pin to ground is 0.42 pF (TPD1E05U06), 0.5 pF (TPD4E05U06) or 0.47 pF (TPD6E05U06). These devices support data rates up to 6 Gbps.

6.3.5 DC Breakdown Voltage

The DC breakdown voltage of each I/O pin is a minimum of 6.5V, which protects sensitive equipment from surges above the reverse standoff voltage of 5.5V.

6.3.6 Ultra-Low Leakage Current

The I/O pins feature an ultra-low leakage current of 10 nA (maximum) with a bias of 2.5 V.

6.3.7 Low ESD Clamping Voltage

The I/O pins feature an ESD clamp that is capable of clamping the voltage to 10 V ($I_{PP} = 1$ A).

6.3.8 Industrial Temperature Range

This device features an industrial operating range of -40°C to $+125^{\circ}\text{C}$.

6.3.9 Easy Flow-Through Routing

The layout of this device makes it simple and easy to add protection to an existing layout. The package offers flow-through routing, requiring minimal modification to an existing layout.

6.4 Device Functional Modes

The TPDxE05U06 is a passive integrated circuit that triggers when voltages are above VBR or below the lower diodes V_f (-0.6 V). During ESD events, voltages as high as ± 15 kV (air) can be directed to ground via the internal diode network. When the voltages on the protected line fall below the trigger levels of TPDxE05U06 (usually within 10s of nano-seconds) the device reverts to passive.

7 Application and Implementation

注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくこととなります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

7.1 Application Information

The TPDxE05U06 is a diode type TVS which is typically used to provide a path to ground for dissipating ESD events on hi-speed signal lines between a human interface connector and a system. As the current from ESD passes through the TVS, only a small voltage drop is present across the diode. This is the voltage presented to the protected IC. The low R_{DYN} of the triggered TVS holds this voltage, V_{CLAMP} , to a safe level for the protected IC.

7.2 Typical Applications

7.2.1 HDMI 2.0 Application

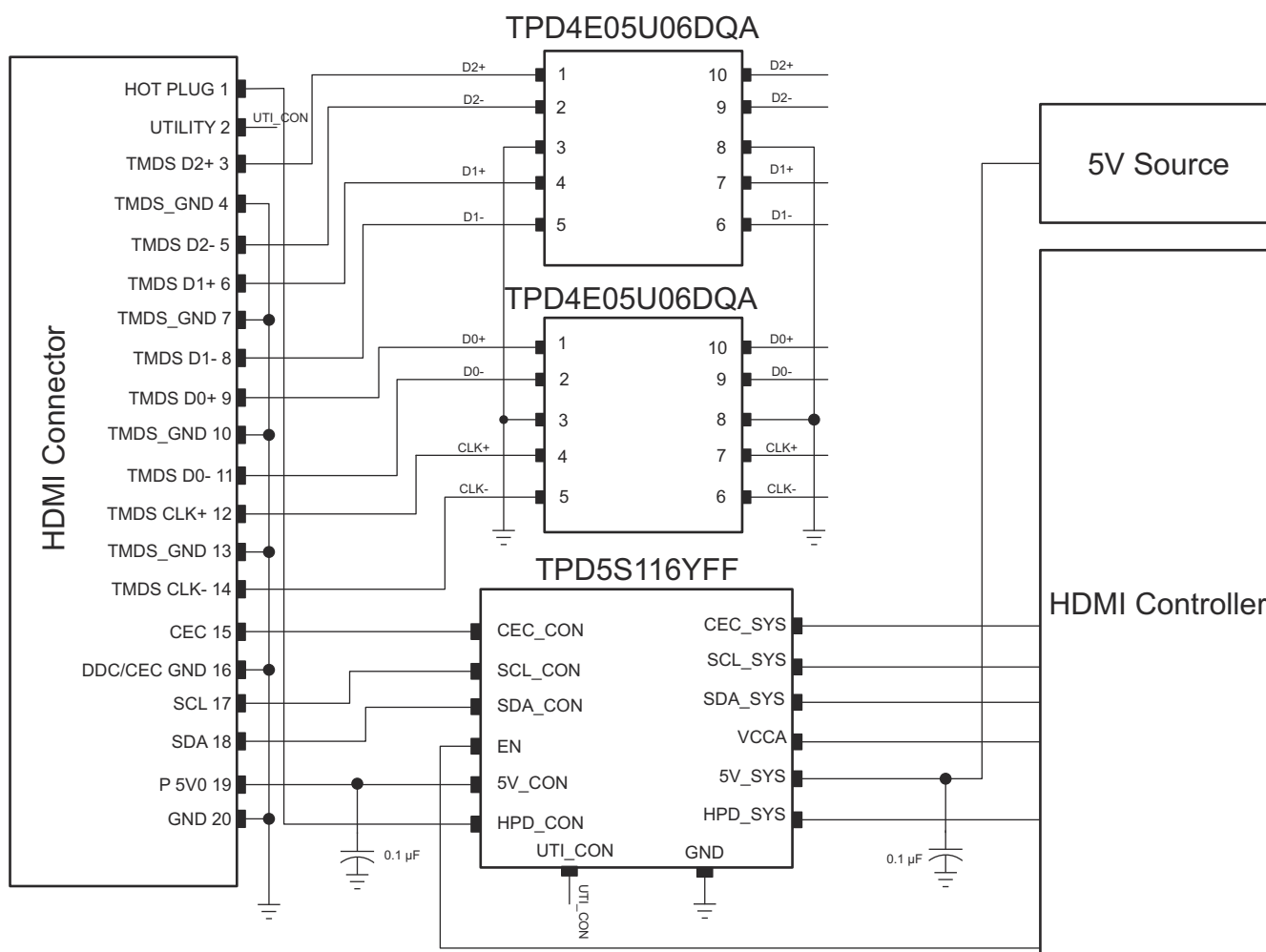


図 7-1. HDMI 2.0 Schematic

7.2.1.1 Design Requirements

For this design example, the two TPD4E05U06 devices, and a TPD5S116 are being used in an HDMI 2.0 application. This provides a complete port protection scheme.

Given the HDMI 2.0 application, the parameters listed in 表 7-1 are known.

表 7-1. Design Parameters

DESIGN PARAMETER	VALUE
Signal range on pins 1, 2, 4, or 5	0 V to 5 V
Operating frequency	3 GHz

7.2.1.2 Detailed Design Procedure

7.2.1.2.1 Signal Range on Pin 1, 2, 4, or 5

The TPD4E05U06 has 4 identical protection channels for signal lines. The symmetry of the device provides flexibility when selecting which of the 4 I/O channels is going to protect which signal lines. Any I/O supports a signal range of 0 to 5.5 V.

7.2.1.3 Application Curves

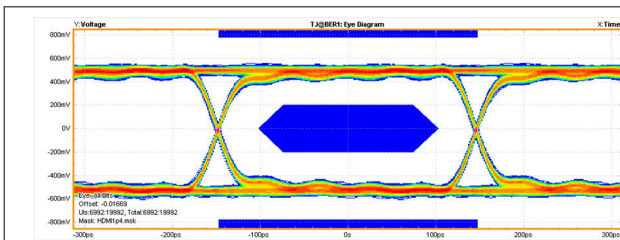


図 7-2. 3.4-Gbps HDMI 1.4 TP1 Eye Diagram Unpopulated EVM

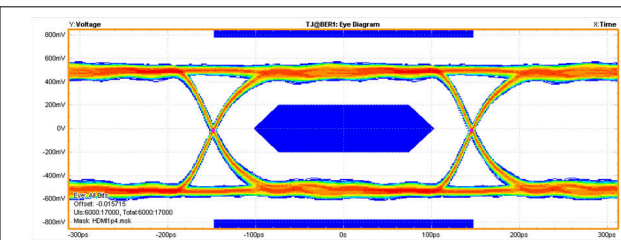


図 7-3. 3.4-Gbps HDMI 1.4 TP1 Eye Diagram TPD1E05U06

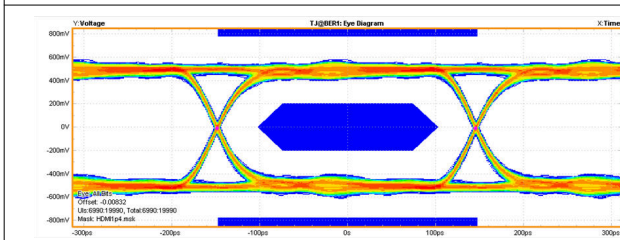


図 7-4. 3.4-Gbps HDMI 1.4 TP1 Eye Diagram TPD4E05U06

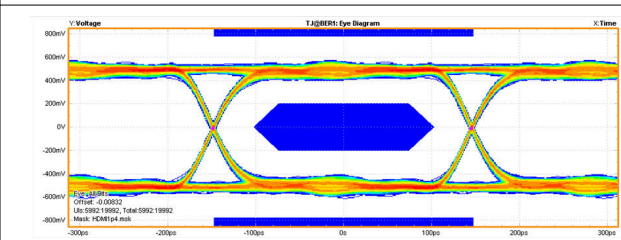


図 7-5. 3.4-Gbps HDMI 1.4 TP1 Eye Diagram TPD6E05U06

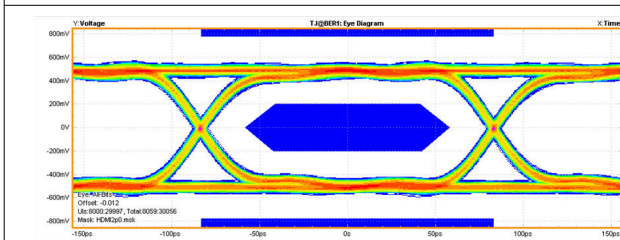


図 7-6. 6-Gbps HDMI 2.0 (TP1) Eye Diagram Unpopulated EVM

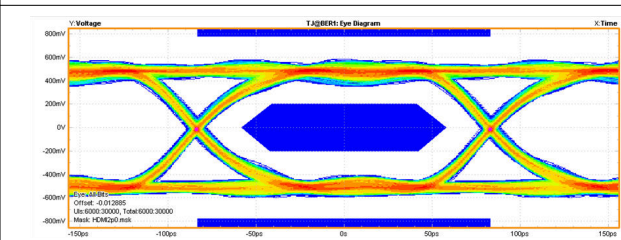
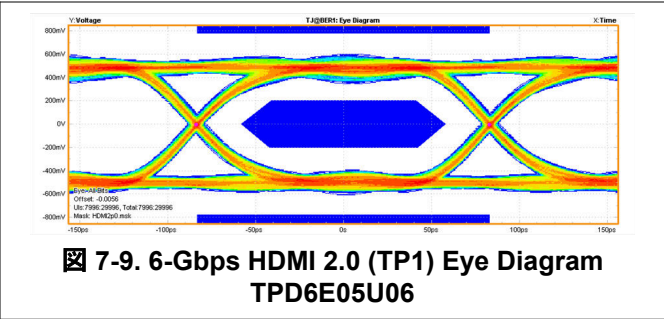
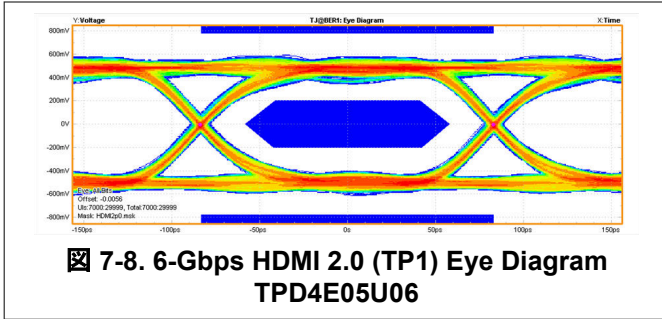
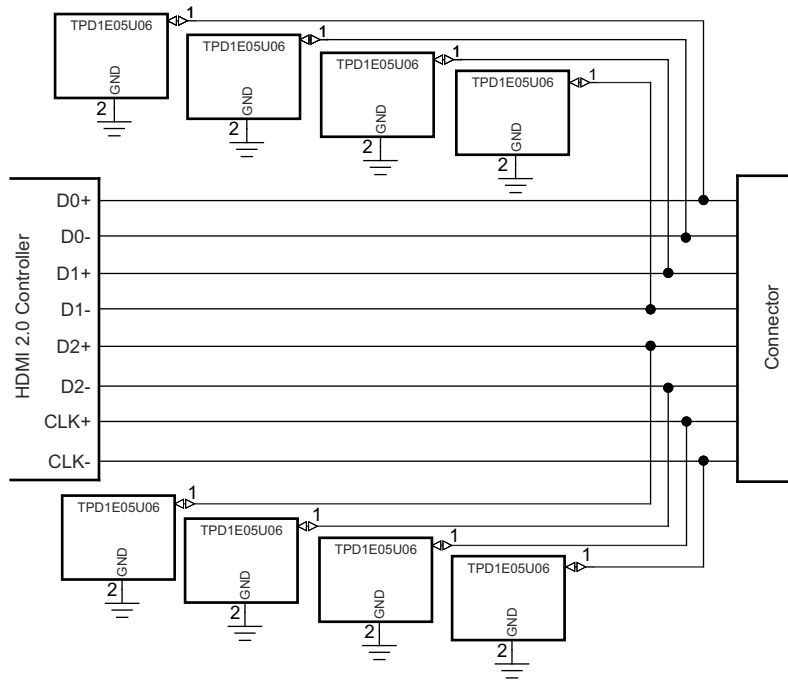


図 7-7. 6-Gbps HDMI 2.0 (TP1) Eye Diagram TPD1E05U06



7.2.2 HDMI 2.0 Application



7-10. HDMI 2.0 Schematic

7.2.2.1 Design Requirements

For this design example, the TPD1E05U06 and the TPD5S116 are used to protect the data pairs and control lines of the HDMI 2.0 connection. This provides full HDMI 2.0 port protection.

Given the HDMI 2.0 application, the following parameters in 表 7-2 are known.

表 7-2. Design Parameters

DESIGN PARAMETER	VALUE
Signal range on data lines	0 V to 5 V
Operating frequency	3 GHz

7.2.2.2 Detailed Design Procedure

7.2.2.2.1 Signal Range

The TPD1E05U06 has 1 protection channel for signal lines, supporting a signal range of 0 V to 5.5 V.

7.2.2.2.2 Operating Frequency

The TPD1E05U06 has 0.42 pF of capacitance, which supports HDMI 2.0 data rates.

7.2.2.3 Application Curves

Refer to the [セクション 7.2.1.3](#) section.

7.3 Power Supply Recommendations

This device is a passive ESD protection device and there is no need to power it. Care must be taken to make sure that the maximum voltage specifications for each line are not violated.

7.4 Layout

7.4.1 Layout Guidelines

- The optimum placement is as close to the connector as possible.
 - EMI during an ESD event can couple from the trace being struck to other nearby unprotected traces, resulting in early system failures.
 - The PCB designer needs to minimize the possibility of EMI coupling by keeping any unprotected traces away from the protected traces which are between the TVS and the connector.
- Route the protected traces as straight as possible.
- Eliminate any sharp corners on the protected traces between the TVS and the connector by using rounded corners with the largest radii possible.
 - Electric fields tend to build up on corners, increasing EMI coupling.

7.4.2 Layout Example

7.4.2.1 TPD4E05U06 Layout Example

This application is typical of an HDMI 1.4 layout.

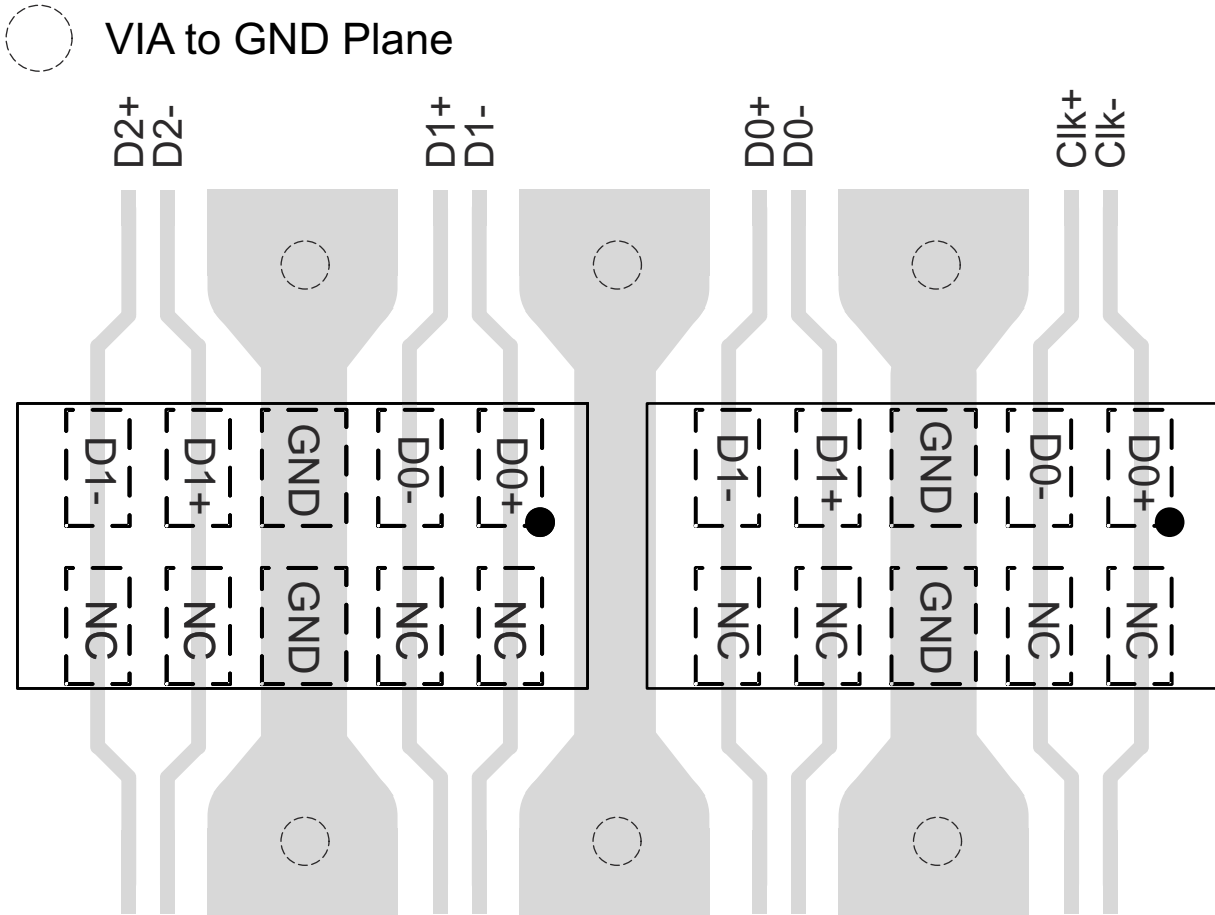


図 7-11. TPD4E05U06 Layout

7.4.2.2 TPD1E05U06 Layout Example

This application is typical of an HDMI 2.0 layout.

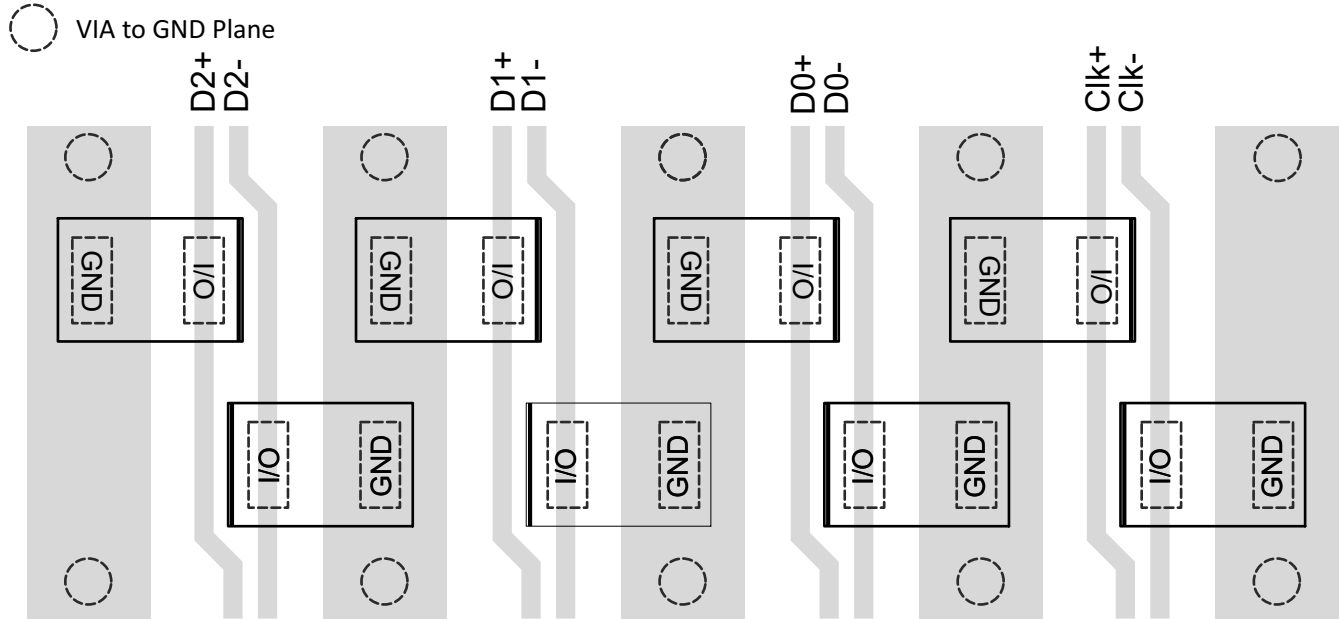


図 7-12. TPD1E05U06 Layout

8 Device and Documentation Support

8.1 Documentation Support

8.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Reading and Understanding an ESD Protection data sheet](#)
- Texas Instruments, [ESD Layout Guide application reports](#)
- Texas Instruments, [TPD6E05U06RVZ EVM user's guide](#)
- Texas Instruments, [Picking ESD Diodes for Ultra High-Speed Data Lines application reports](#)
- Texas Instruments, [ESD PROTECTION DIODES EVM user's guide](#)
- Texas Instruments, [TPD1E05U06DPY EVM user's guide](#)
- Texas Instruments, [TPD4E05U06DQA EVM user's guide](#)
- Texas Instruments, [Generic ESD Evaluation Module user's guide](#)

8.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

8.3 サポート・リソース

テキサス・インスツルメンツ E2E™ サポート・フォーラムは、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

リンクされているコンテンツは、各寄稿者により「現状のまま」提供されるものです。これらはテキサス・インスツルメンツの仕様を構成するものではなく、必ずしもテキサス・インスツルメンツの見解を反映したものではありません。テキサス・インスツルメンツの[使用条件](#)を参照してください。

8.4 Trademarks

テキサス・インスツルメンツ E2E™ is a trademark of Texas Instruments.
PCI-express® and PCI-Express® are registered trademarks of PCI-SIG .
V-by-One® are registered trademarks of Thine Electronics, Inc.
すべての商標は、それぞれの所有者に帰属します。

8.5 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

8.6 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

9 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision N (February 2022) to Revision O (August 2024)	Page
• 「製品情報」の表を更新.....	1

Changes from Revision M (January 2017) to Revision N (February 2022)

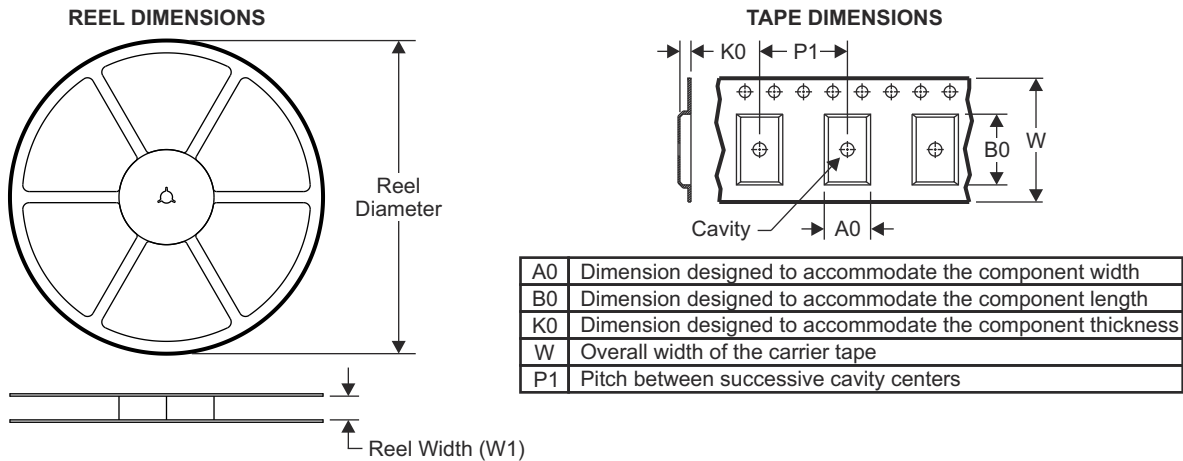
Page

- SOD-523 パッケージ情報を、ボディサイズ (0.8mm × 1.2mm) からリード間寸法 (1.60mm × 0.80mm × 0.65mm) に更新..... 1

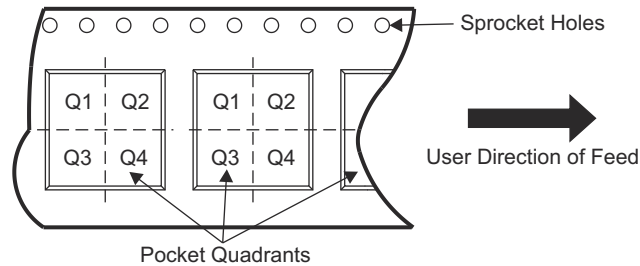
10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

10.1 Tape and Reel Information

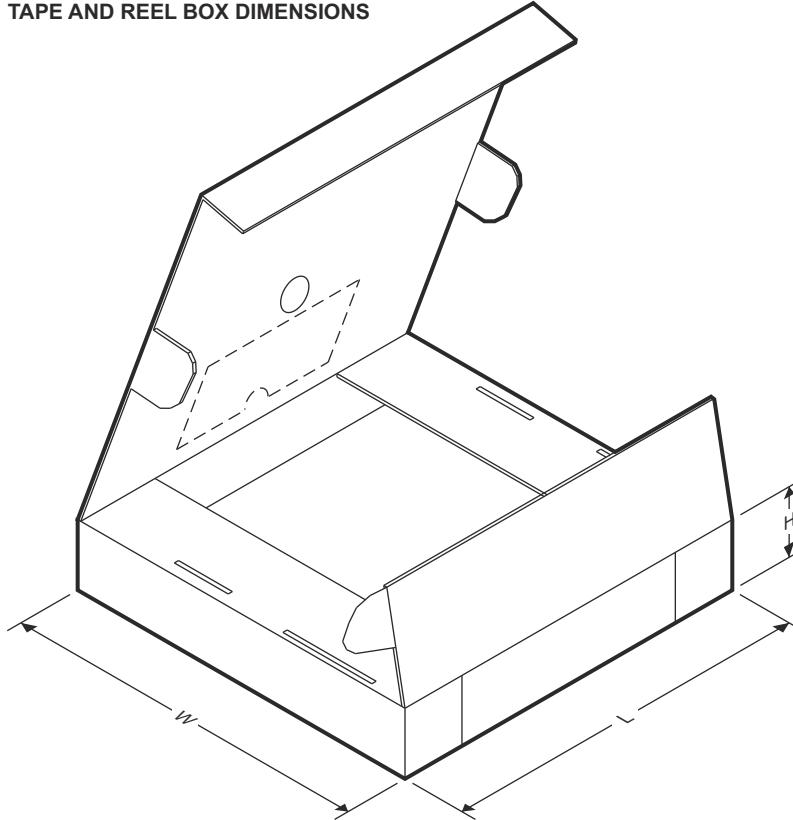


QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPD1E05U06DPYR	X1SON	DPY	2	10000	180.0	8.4	0.67	1.15	0.46	2.0	8.0	Q2
TPD1E05U06DPYT	X1SON	DPY	2	250	180.0	9.5	0.66	1.15	0.66	2.0	8.0	Q1
TPD1E05U06DYAR	SOT-5X3	DYA	2	3000	178.0	9.5	0.5	1.94	0.73	2.0	8.0	Q1
TPD4E05U06DQAR	USON	DQA	10	3000	180.0	8.4	1.2	2.7	0.63	4.0	8.0	Q1
TPD6E05U06RVZR	USON	RVZ	14	3000	180.0	13.2	1.65	3.8	0.7	4.0	12.0	Q1
TPD6E05U06RVZR	USON	RVZ	14	3000	178.0	13.5	1.6	3.75	0.7	4.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

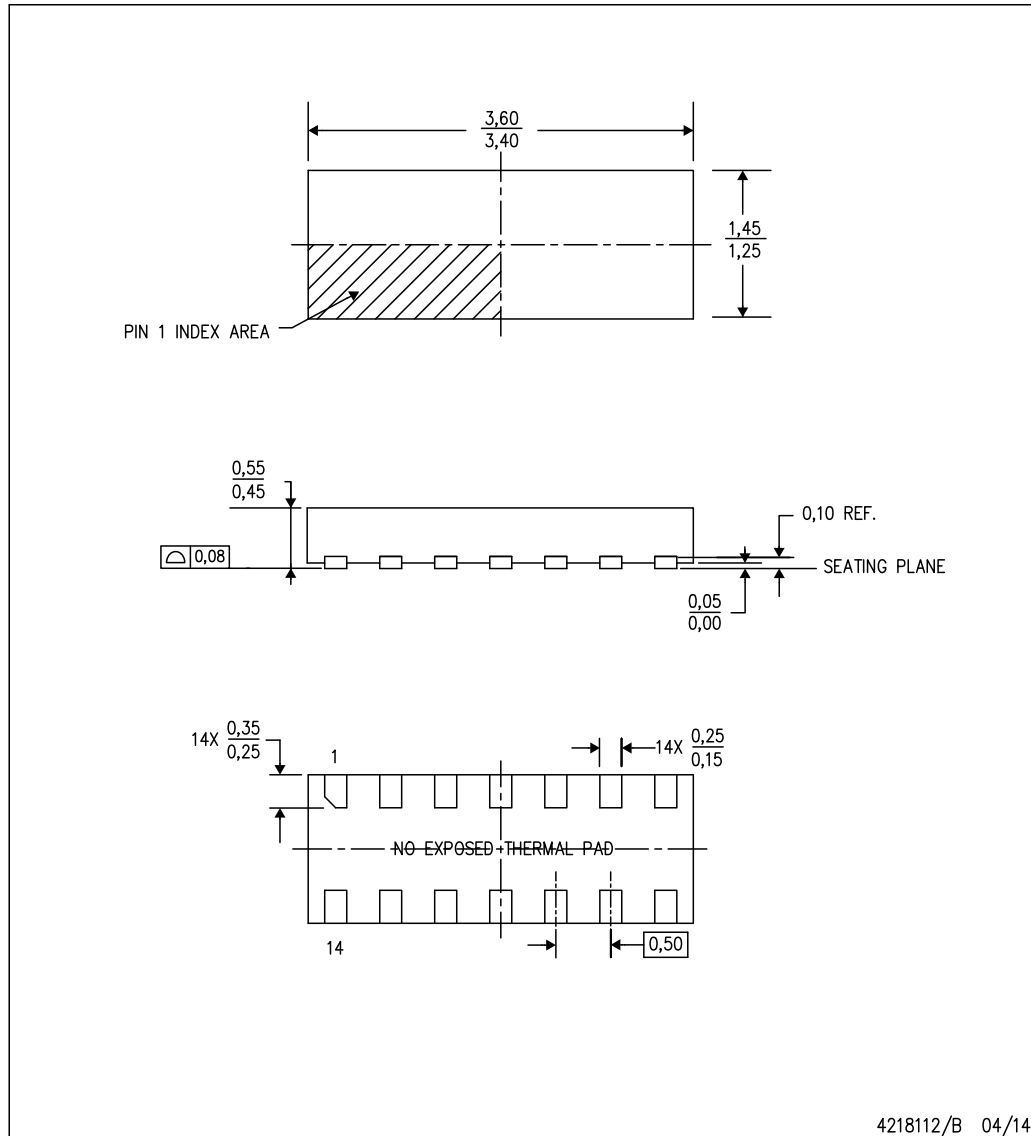


Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPD1E05U06DPYR	X1SON	DPY	2	10,000	210.000	185.000	35.000
TPD1E05U06DPYT	X1SON	DPY	2	250	184.0	184.0	19.0
TPD1E05U06DYAR	SOT-5X3	DYA	2	3000	210.0	200.0	42.0
TPD4E05U06DQAR	USON	DQA	10	3000	210.0	185.0	35.0
TPD6E05U06RVZR	USON	RVZ	14	3000	189.0	185.0	36.0
TPD6E05U06RVZR	USON	RVZ	14	3000	184.0	184.0	19.0

10.2 Mechanical Data

MECHANICAL DATA

RVZ (R-PUSON-N14) PLASTIC SMALL OUTLINE NO-LEAD

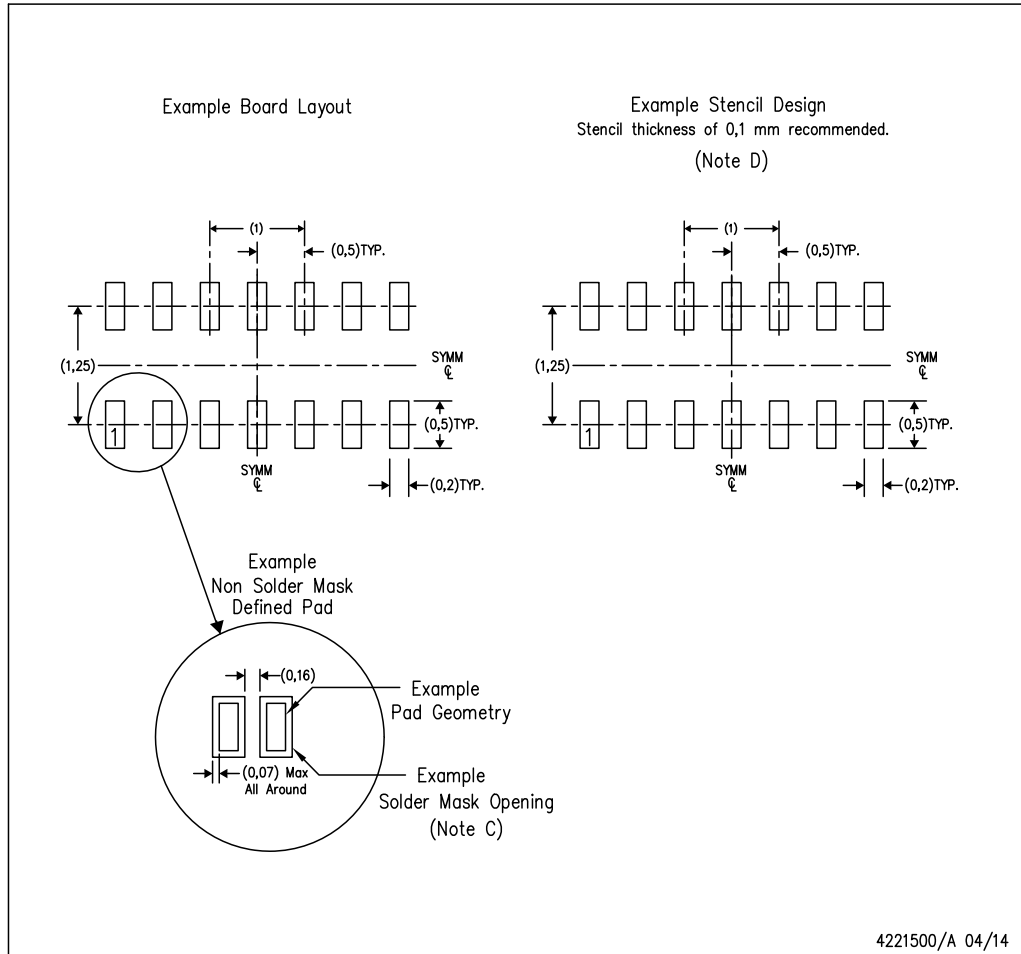


- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-Lead) package configuration.

LAND PATTERN DATA

RVZ (R-PUSON-N14)

PLASTIC SMALL OUTLINE NO-LEAD



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.

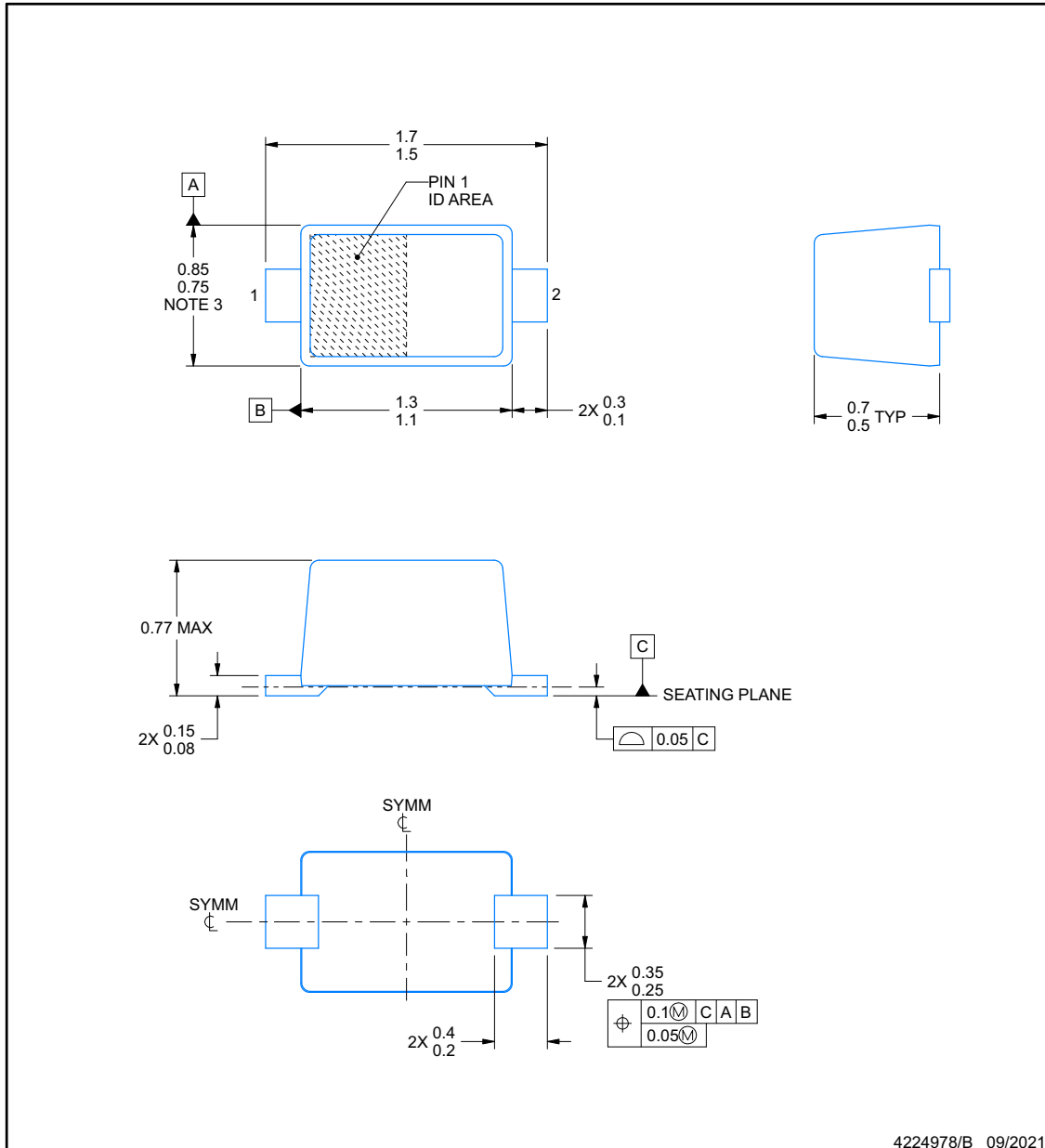


PACKAGE OUTLINE

DYA0002A

SOT (SOD-523) - 0.77 mm max height

PLASTIC SMALL OUTLINE



NOTES:

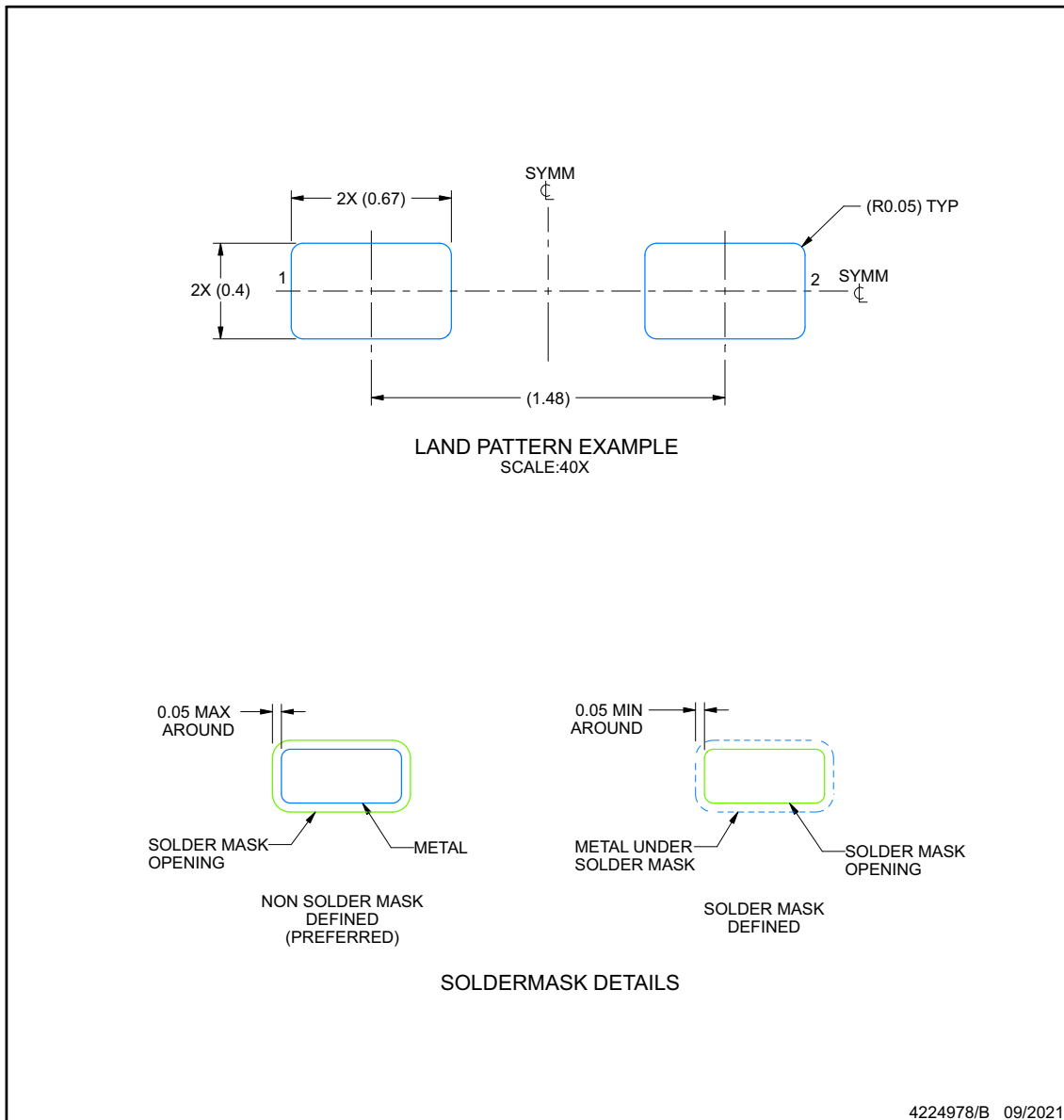
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEITA SC-79 registration except for package height

EXAMPLE BOARD LAYOUT

DYA0002A

SOT (SOD-523) - 0.77 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

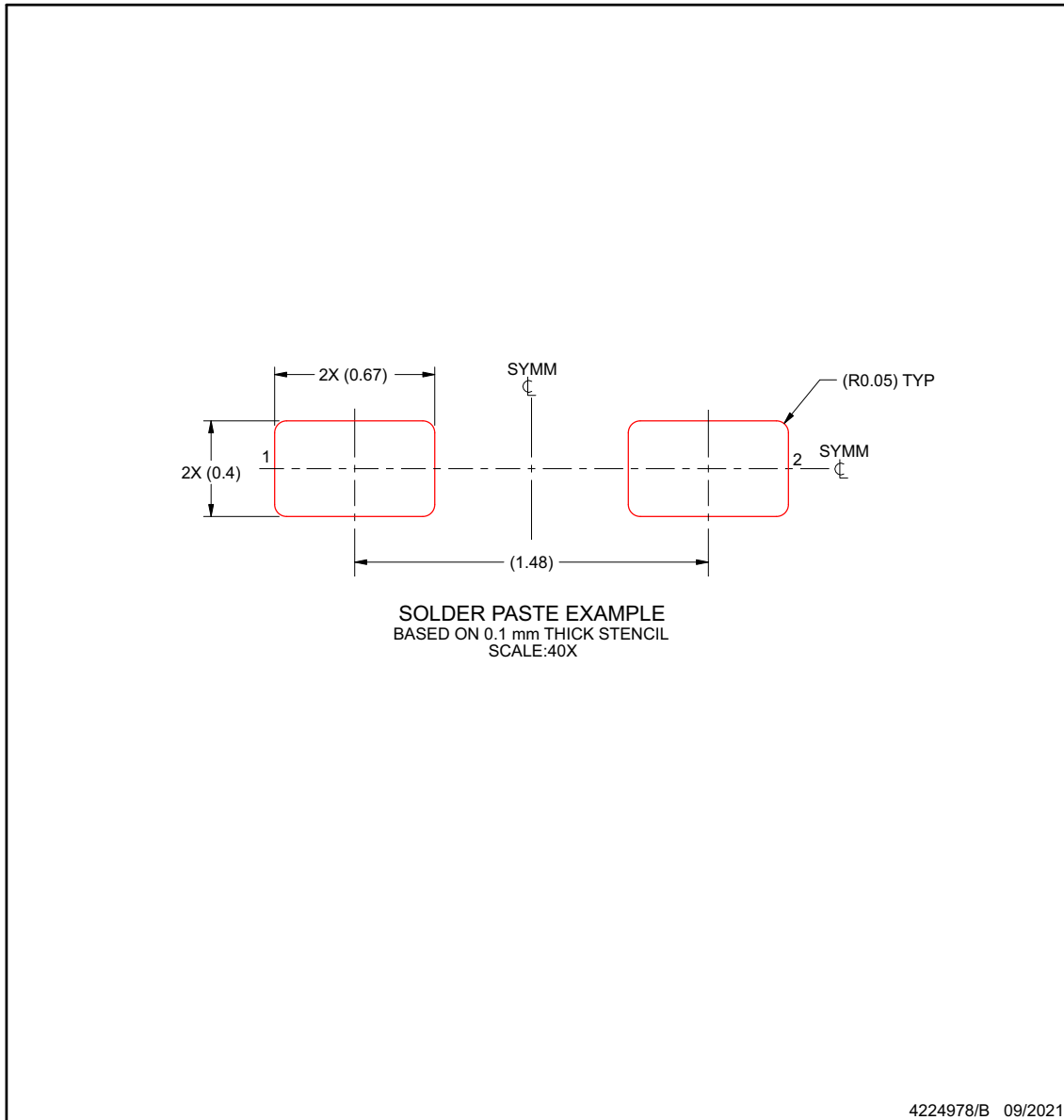
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DYA0002A

SOT (SOD-523) - 0.77 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

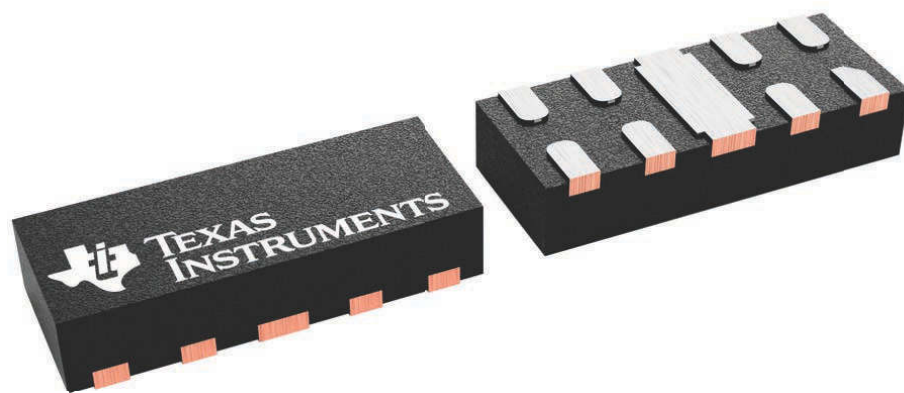
DQA 10

1 x 2.5, 0.5 mm pitch

USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4230320/A

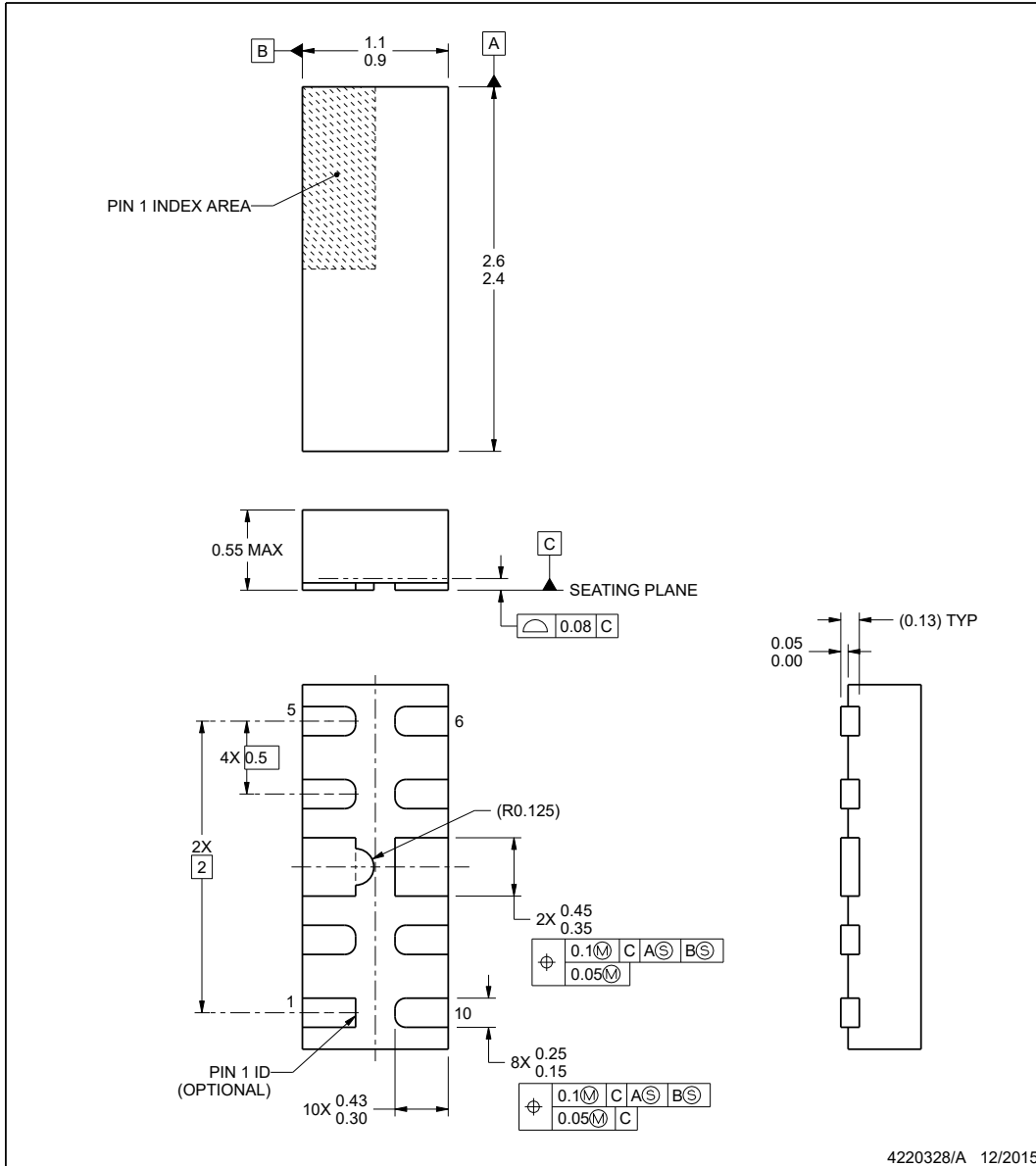




DQA0010A

PACKAGE OUTLINE
USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

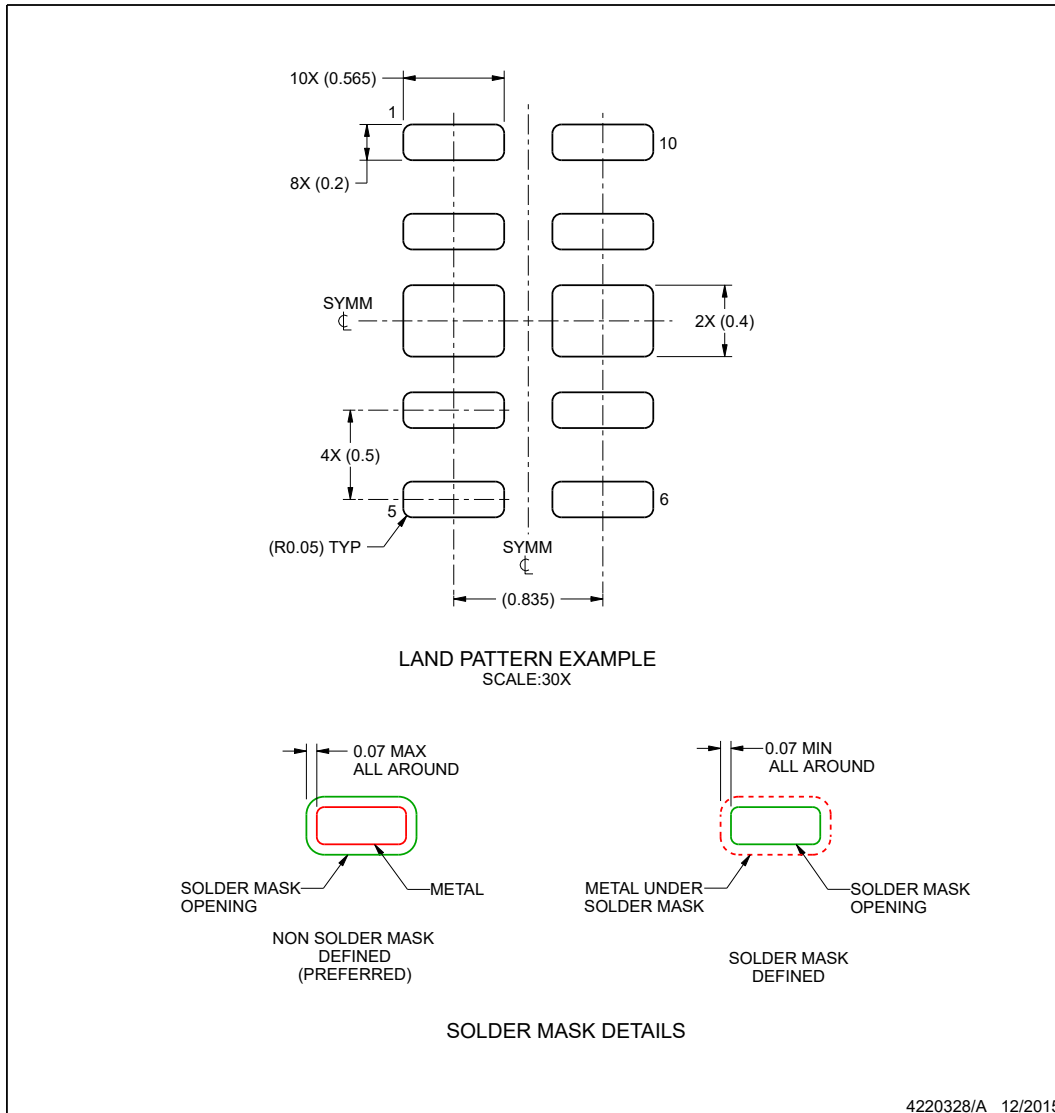
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

DQA0010A

USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

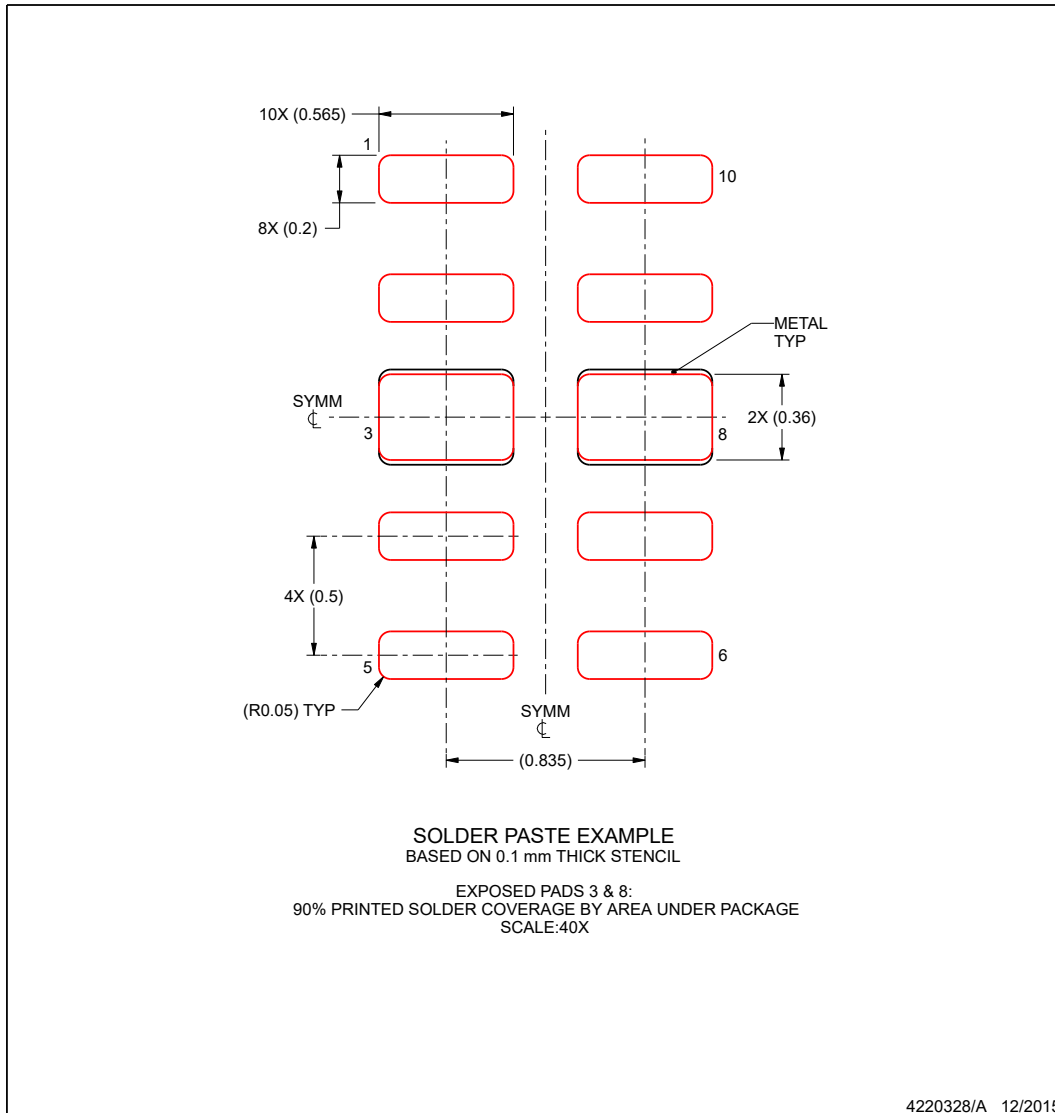
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

DQA0010A

USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

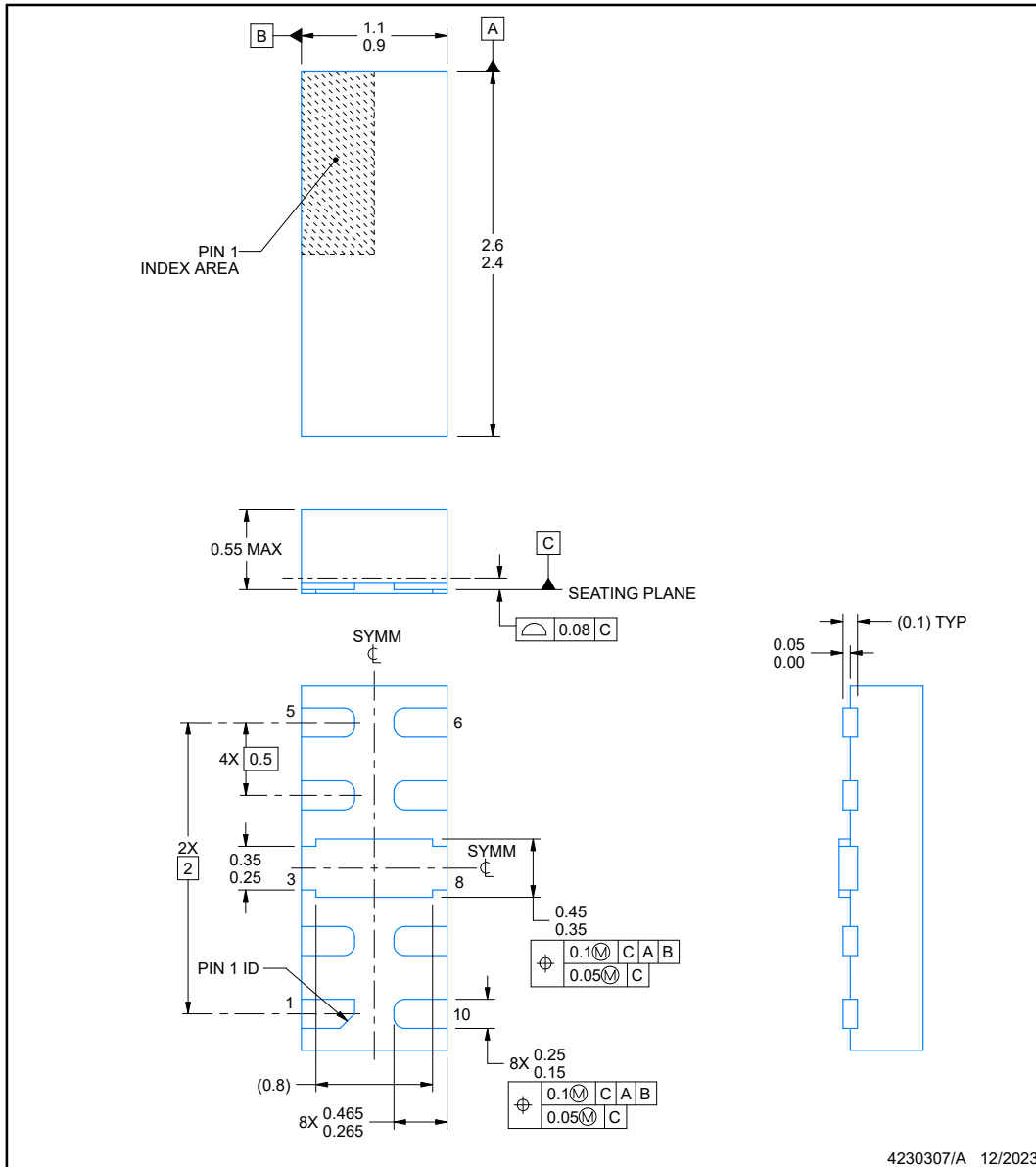


DQA0010B

PACKAGE OUTLINE

USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

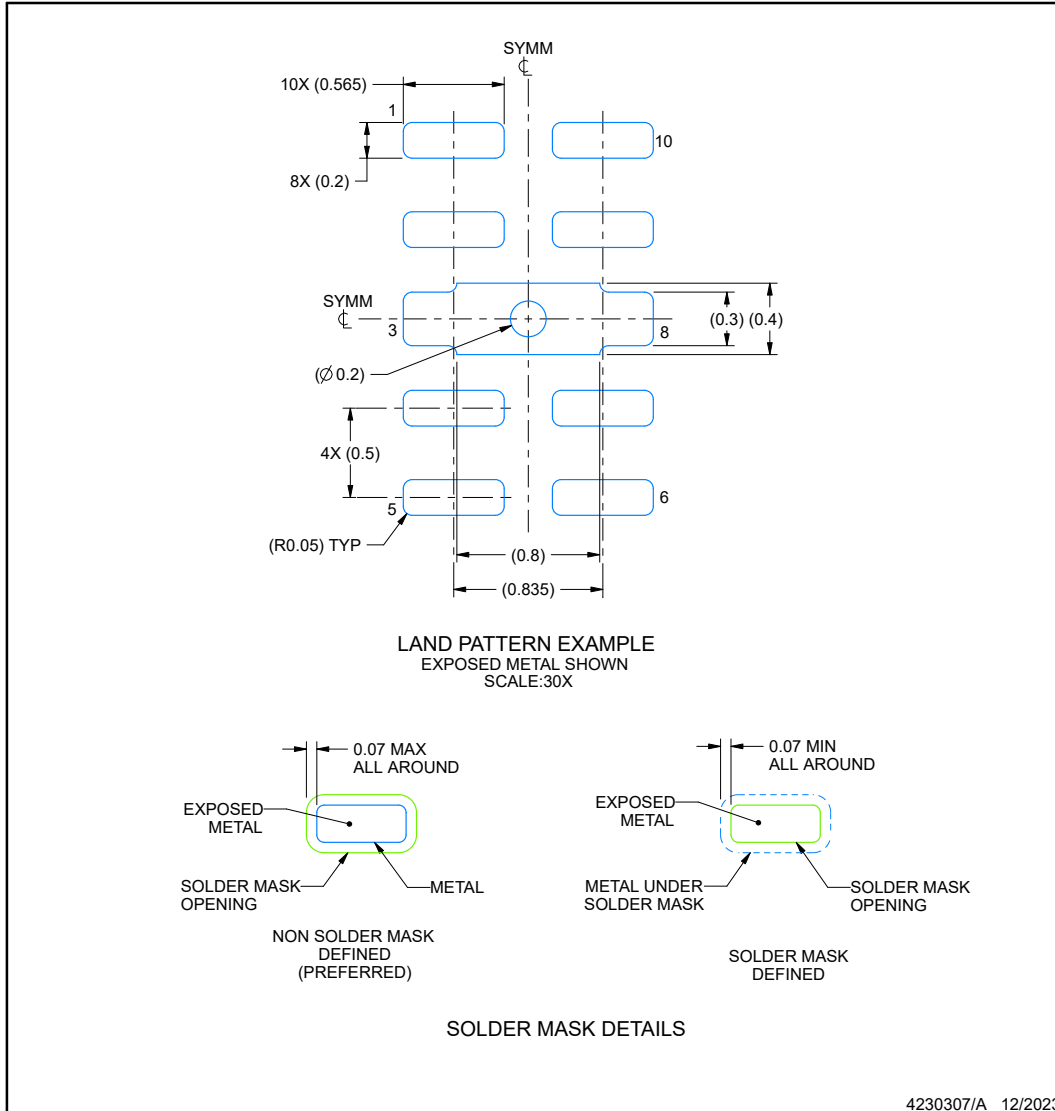
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

DQA0010B

USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

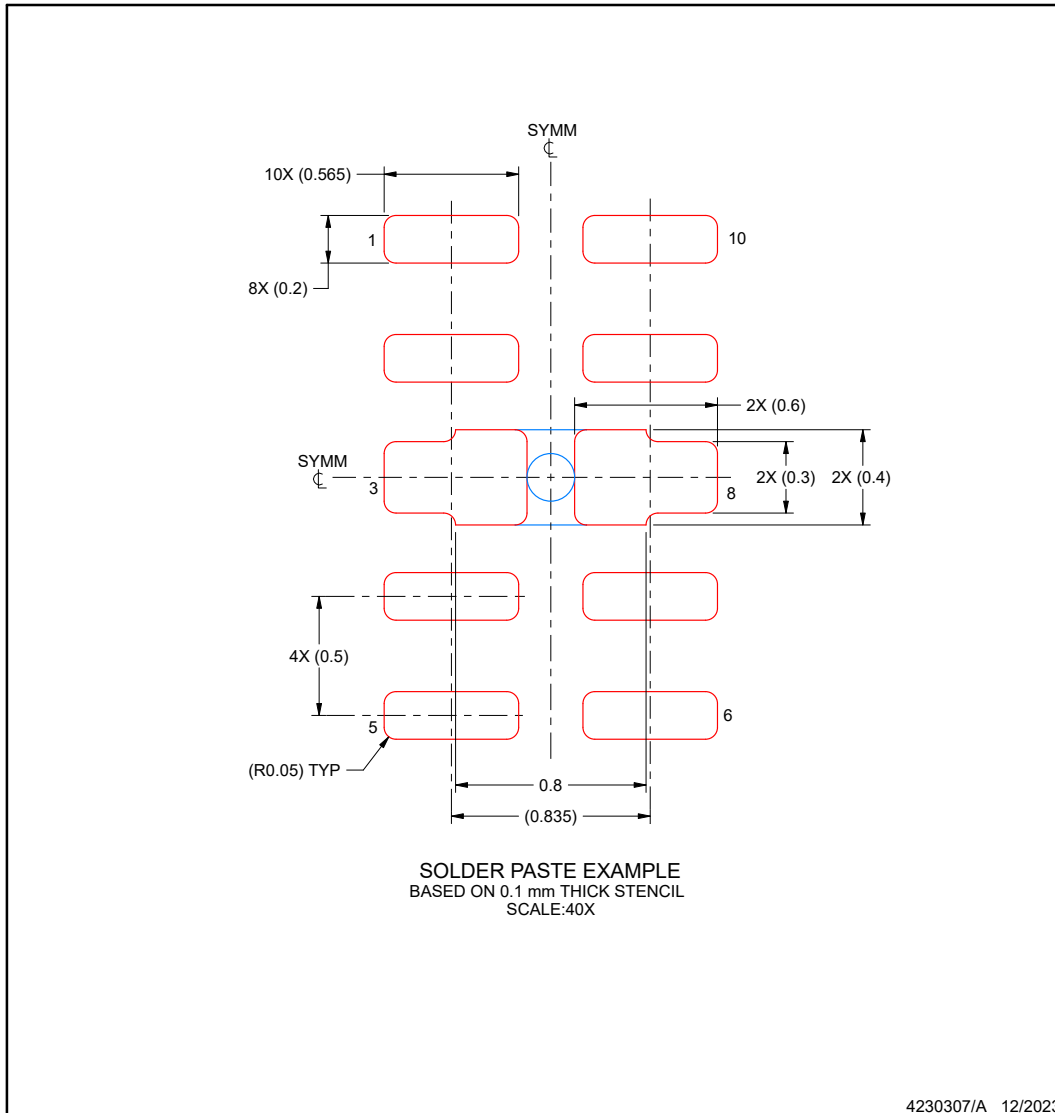
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

DQA0010B

USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

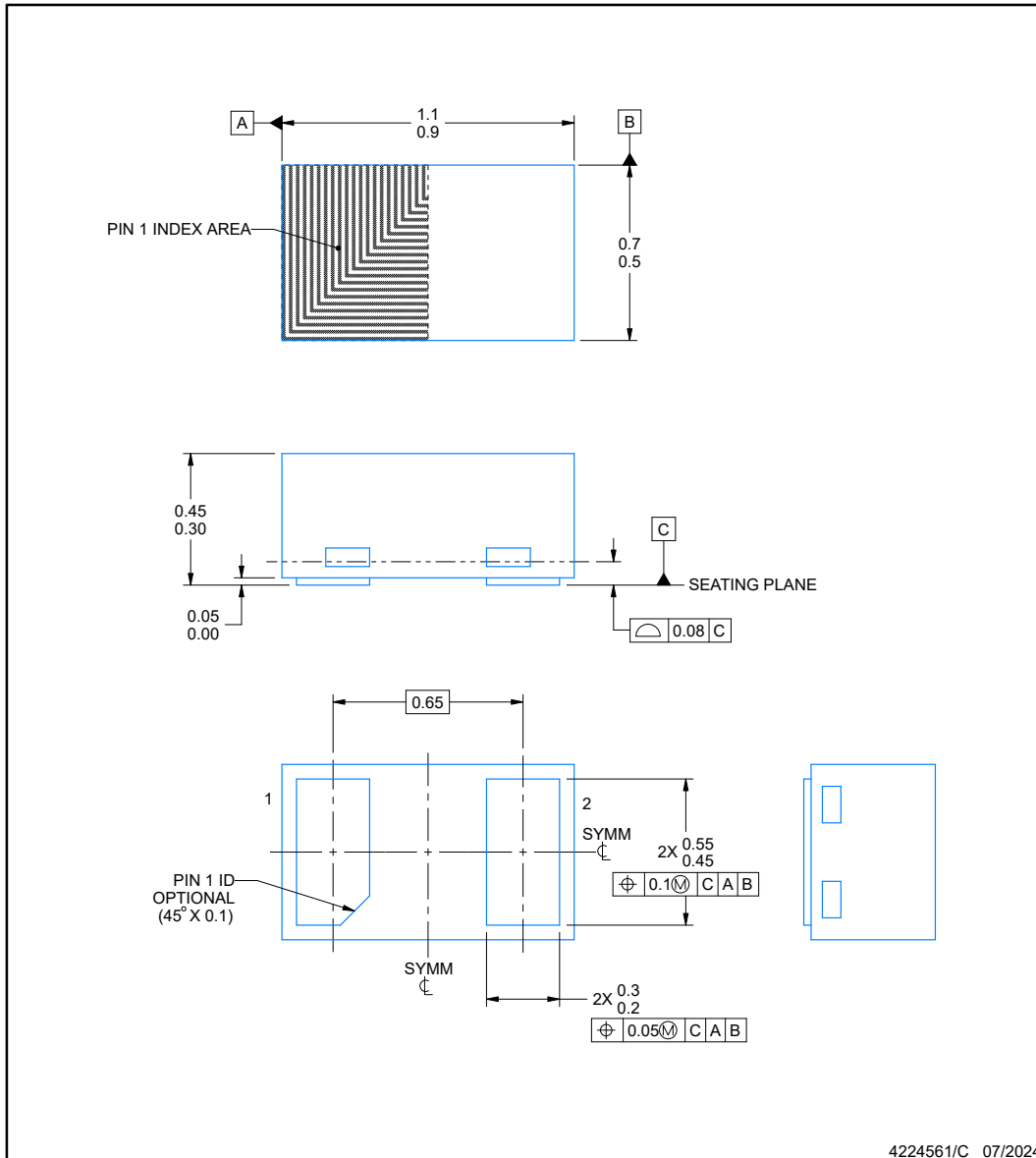


PACKAGE OUTLINE

DPY0002A

X1SON - 0.45 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

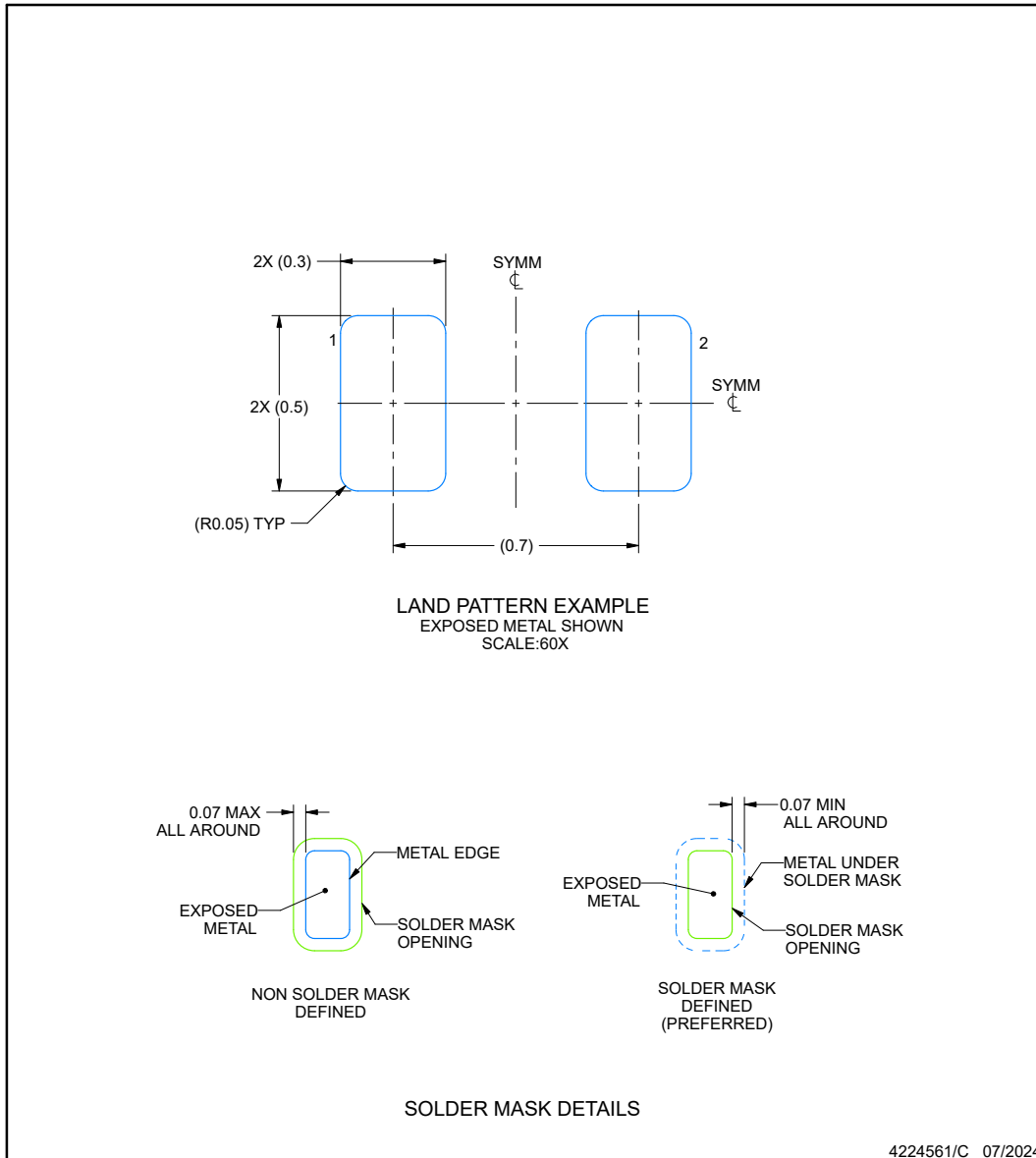
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

DPY0002A

X1SON - 0.45 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

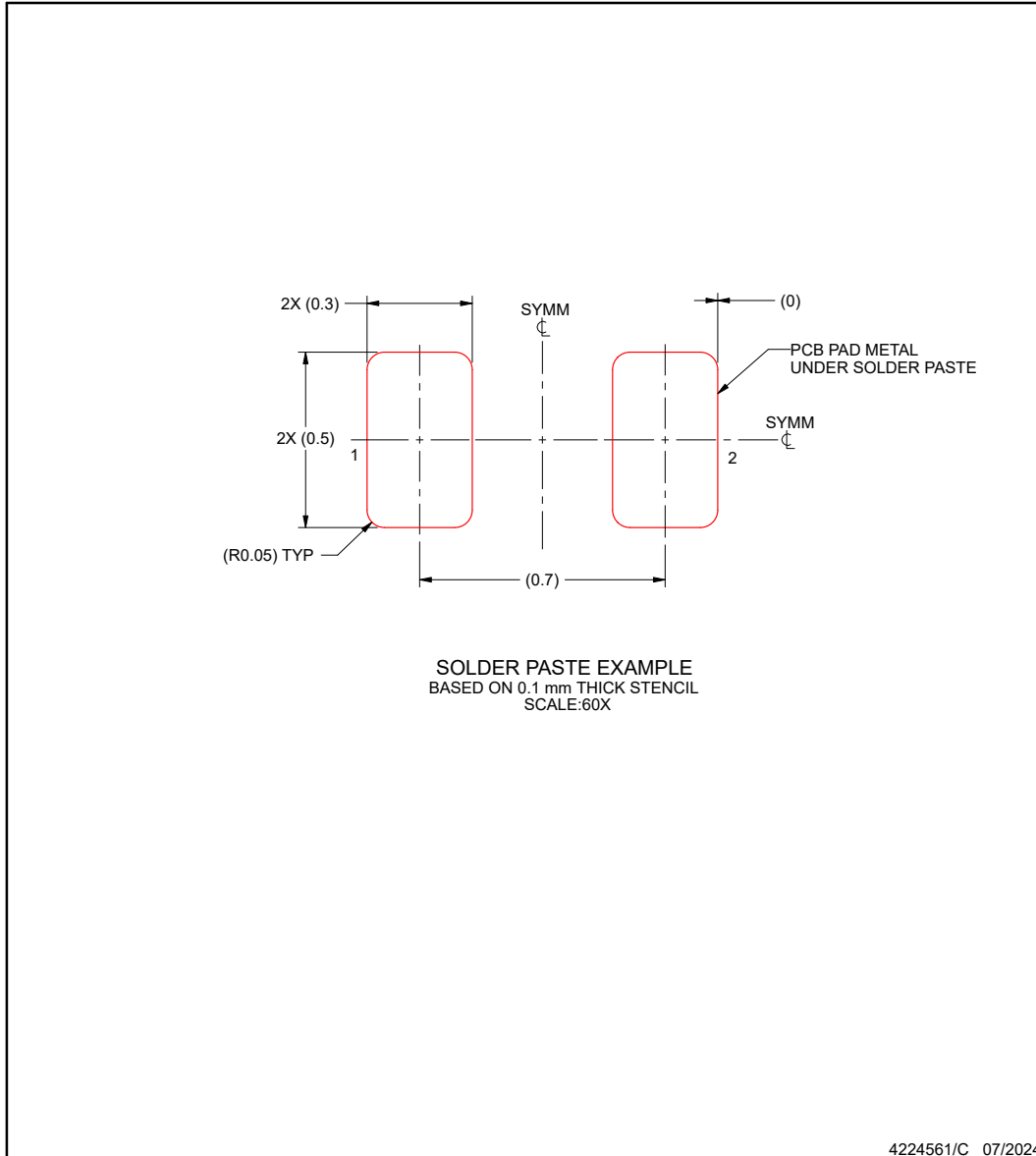
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
4. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DPY0002A

X1SON - 0.45 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

重要なお知らせと免責事項

テキサス・インスツルメンツは、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、テキサス・インスツルメンツ製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した テキサス・インスツルメンツ製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとします。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている テキサス・インスツルメンツ製品を使用するアプリケーションの開発の目的でのみ、テキサス・インスツルメンツはその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。テキサス・インスツルメンツや第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、テキサス・インスツルメンツおよびその代理人を完全に補償するものとし、テキサス・インスツルメンツは一切の責任を拒否します。

テキサス・インスツルメンツの製品は、[テキサス・インスツルメンツの販売条件](#)、または [ti.com](https://www.ti.com) やかかる テキサス・インスツルメンツ製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供されています。テキサス・インスツルメンツがこれらのリソースを提供することは、適用されるテキサス・インスツルメンツの保証または他の保証の放棄の拡大や変更を意味するものではありません。

お客様がいかなる追加条項または代替条項を提案した場合でも、テキサス・インスツルメンツはそれらに異議を唱え、拒否します。

郵送先住所: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

Copyright © 2024, Texas Instruments Incorporated

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPD1E05U06DPYR	ACTIVE	X1SON	DPY	2	10000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(BK, C1, C6) C2	Samples
TPD1E05U06DPYT	ACTIVE	X1SON	DPY	2	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(BK, C1, C6) C2	Samples
TPD1E05U06DYAR	ACTIVE	SOT-5X3	DYA	2	3000	RoHS & Green	SN	Level-3-260C-168 HR	-40 to 125	1KS	Samples
TPD4E05U06DQAR	ACTIVE	USON	DQA	10	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(BLG, BRG, DQA) BRY	Samples
TPD6E05U06RVZR	ACTIVE	USON	RVZ	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(BV, BVY)	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPD1E05U06, TPD4E05U06 :

- Automotive : [TPD1E05U06-Q1](#), [TPD4E05U06-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

重要なお知らせと免責事項

TI は、技術データと信頼性データ(データシートを含みます)、設計リソース(リファレンス・デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、TI 製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した TI 製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとし、

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている TI 製品を使用するアプリケーションの開発の目的でのみ、TI はその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。TI や第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、TI およびその代理人を完全に補償するものとし、TI は一切の責任を拒否します。

TI の製品は、[TI の販売条件](#)、または [ti.com](#) やかかる TI 製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供されています。TI がこれらのリソースを提供することは、適用される TI の保証または他の保証の放棄の拡大や変更を意味するものではありません。

お客様がいかなる追加条項または代替条項を提案した場合でも、TI はそれらに異議を唱え、拒否します。

郵送先住所 : Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2024, Texas Instruments Incorporated